

PATENT APPLICATION
Docket No. 4591-247
Client No. IB12109-US

Applicant: Sung-Ho Kim
Serial No. not yet assigned Examiner: not yet assigned
Filing Date: October 7, 2003 Group: not yet assigned
Title: NONVOLATILE MEMORY DEVICE HAVING ASYMMETRIC SOURCE/DRAIN REGION AND FABRICATING METHOD THEREOF

INFORMATION DISCLOSURE CITATION
FORM PTO-1449 (Modified)

U.S. PATENT DOCUMENTS

<u>Exam</u>	<u>Document</u>	<u>Issue</u>	<u>Name</u>	<u>Class</u>	<u>Sub</u>
<u>Init</u>	<u>Number</u>	<u>Date</u>	<u>Name</u>		<u>Class</u>

FOREIGN PATENT DOCUMENTS

<u>Exam</u>	<u>Document</u>	<u>Publication</u>	<u>Country</u>	<u>Name</u>
<u>Init</u>	<u>Number</u>	<u>Date</u>	<u>Country</u>	<u>Name</u>

OTHER DOCUMENTS

<u>Exam</u>	<u>Author, Title, Date, Pertinent Pages, Etc.)</u>
<u>Init</u>	<u>Ref</u>

English language of abstract from Korean Patent Publication No. 2001-91532,
filed 10/23/2001.

Examiner: _____

Date Considered: _____